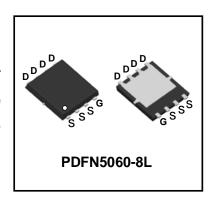


# **40V N-Channel Enhancement Mode Power MOSFET**

# **Description**

WMB018N04LG4 uses Wayon's 4<sup>th</sup> generation power trench MOSFET technology that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance. This device is well suited for high efficiency fast switching applications.



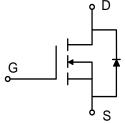
#### **Features**

- $V_{DS} = 40V$ ,  $I_D = 200A$   $R_{DS(on)} < 1.7m\Omega$  @  $V_{GS} = 10V$  $R_{DS(on)} < 2.3m\Omega$  @  $V_{GS} = 4.5V$
- Low R<sub>DS</sub>(on)
- Green Device Available
- 100% EAS Guaranteed
- RoHS Compliant & Halogen-Free

# **Applications**

- Power Management Switches
- DC/DC Converter





## Absolute Maximum Ratings (T<sub>A</sub> = 25°C, unless otherwise noted)

Parameter		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DS</sub>	40	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	V	
Continuous Dunis Courset	T <sub>C</sub> =25°C	I <sub>D</sub>	200	•	
Continuous Drain Current	Tc=100°C		126.6	А	
Pulsed Drain Current <sup>1</sup>		Ідм	800	А	
Single Pulse Avalanche Energy <sup>2</sup>		EAS	273.8	mJ	
Total Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	104	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C	

#### **Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction-to-Ambient <sup>3</sup>	R <sub>0JA</sub>	50	°C/W
Thermal Resistance from Junction-to-Case	R <sub>θJC</sub>	1.2	°C/W



## Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise noted)

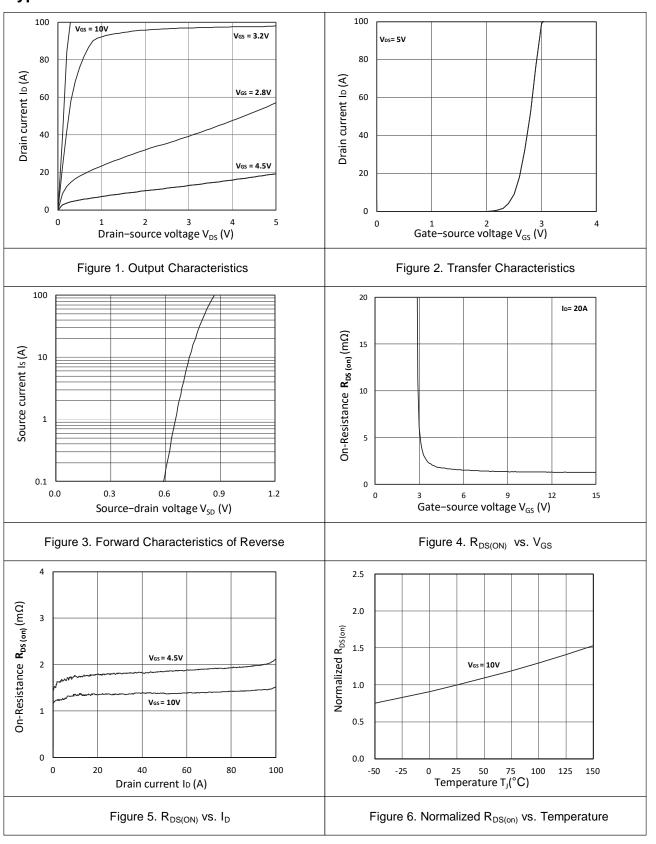
Parameter		Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static Characteristics				•	•			
Drain-Source Breakdown Voltage		V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	40	-	-	V	
Gate-body Leakage Current		Igss	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA	
Zero Gate Voltage Drain Current	T <sub>J</sub> =25°C	1	\/ 40\/ \/ 0\/	-	-	1	μА	
	T <sub>J</sub> =100°C	- I <sub>DSS</sub>	$V_{DS} = 40V$ , $V_{GS} = 0V$	-	-	100		
Gate-Threshold Voltage		V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	1.2	1.7	2.2	V	
		_	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	-	1.35	1.7		
Drain-Source on-Resistance <sup>4</sup>		R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	-	1.75	2.3	mΩ	
Forward Transconductance <sup>4</sup>		<b>G</b> fs	V <sub>DS</sub> = 10V, I <sub>D</sub> =20A	-	121	-	S	
Dynamic Characteristics5								
Input Capacitance		Ciss		-	3480	-		
Output Capacitance		Coss	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	-	815	-	pF	
Reverse Transfer Capacitance		Crss		-	50	-		
Gate Resistance		R <sub>G</sub>	f = 1MHz	-	0.9	-	Ω	
Switching Characteristics	5							
Total Gate Charge		Qg		-	54	-	nC	
Gate-Source Charge		$Q_{\mathrm{gs}}$	$V_{GS} = 10V, V_{DS} = 20V,$ $I_{D} = 20A$	-	9.5	-		
Gate-Drain Charge		$\mathbf{Q}_{gd}$		-	7.3	-		
Turn-on Delay Time		t <sub>d(on)</sub>		-	10.4	-	. ns	
Rise Time		tr	$V_{GS} = 10V, V_{DD} = 20V,$	-	8	-		
Turn-off Delay Time		t <sub>d(off)</sub>	$R_G = 3\Omega$ , $I_D = 20A$	-	37.6	-		
Fall Time		t <sub>f</sub>		-	12.1	-		
Body Diode Reverse Recovery Time		t <sub>rr</sub>	1 000 1:/-14 4000/	-	50	-	ns	
Body Diode Reverse Recovery Charge		Q <sub>rr</sub>	- I <sub>F</sub> = 20A, di/dt = 100A/μs	-	20	-	nC	
Drain-Source Body Diode	Characteris	stics						
Diode Forward Voltage <sup>4</sup>		V <sub>SD</sub>	Is = 20A, V <sub>GS</sub> = 0V	-	-	1.2	V	
Continuous Source Current Tc=25°C		Is	-	-	-	200	Α	

#### Notes:

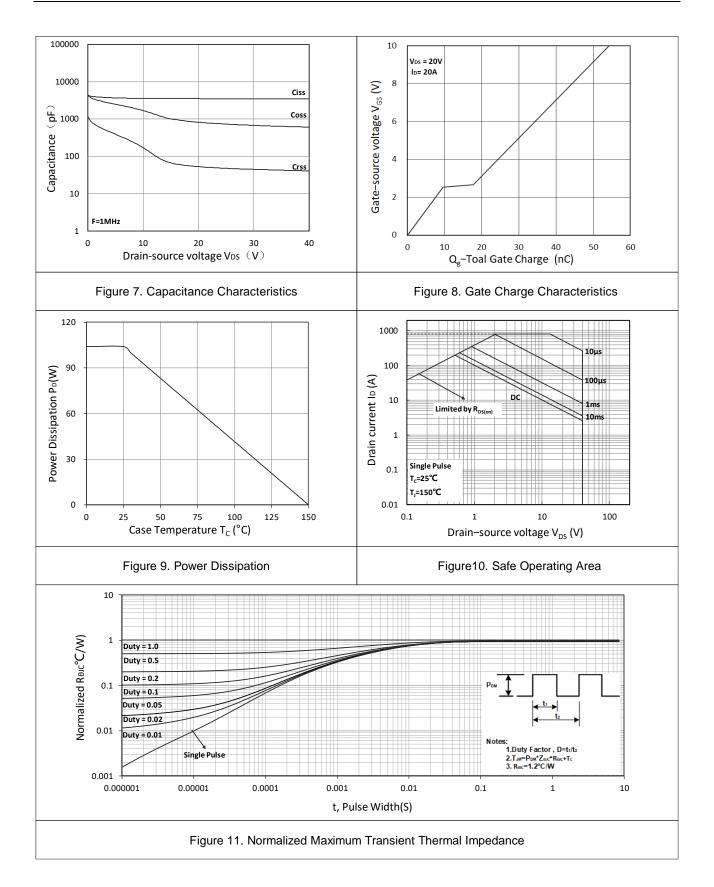
- 1. Repetitive rating, pulse width limited by junction temperature  $T_{\text{J(MAX)}}$ =150°C.
- 2. The test condition is  $V_{DD}$ =25V, $V_{GS}$ =10V,L=0.4mH,  $I_{AS}$ =37A.
- 3. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
- 4. The data tested by pulsed, pulse width  $\leq$  300us , duty cycle  $\leq$  2%.
- 5. This value is guaranteed by design hence it is not included in the production test.



## **Typical Characteristics**









### **Test Circuit**

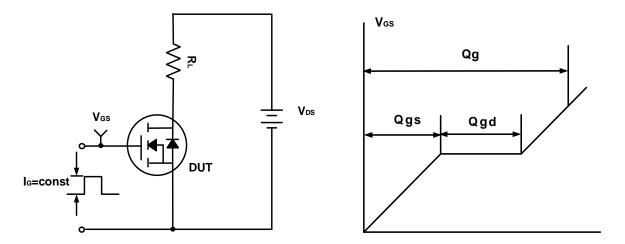


Figure A. Gate Charge Test Circuit & Waveforms

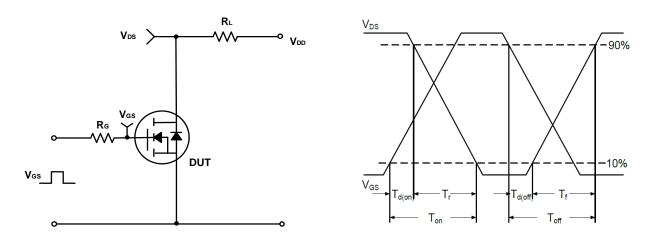


Figure B. Switching Test Circuit & Waveforms

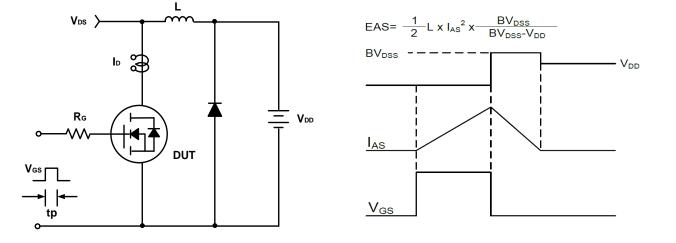
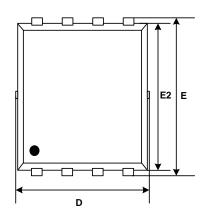
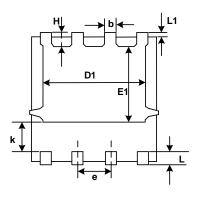


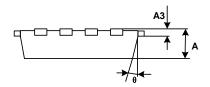
Figure C. Unclamped Inductive Switching Circuit & Waveforms



### **Mechanical Dimensions for PDFN5060-8L**







### **COMMON DIMENSIONS**

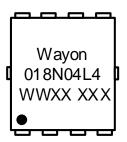
CVMDOL	MM			
SYMBOL	MIN	MAX		
Α	0.90	1.20		
А3	0.15	0.35		
D	4.80	5.40		
Е	5.90	6.35		
D1	3.61	4.31		
E1	3.30	3.92		
E2	5.50	6.06		
k	1.10	-		
b	0.30	0.51		
e	1.27BSC			
L	0.38	0.71		
L1	0.05	0.36		
Н	0.38	0.71		
θ	0°	12°		



## **Ordering Information**

Part	Package	Marking	Packing method
WMB018N04LG4	PDFN5060-8L	018N04L4	Tape and Reel

## **Marking Information**



018N04L4 = Device code

WWXX XXX= Date code

## **Contact Information**

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WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

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### **Product Specification Statement**

- 1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.
- 2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.
- 3. WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.
- 4. Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.
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